

FML16N50ES

FUJI POWER MOSFET

Super FAP-E³ series

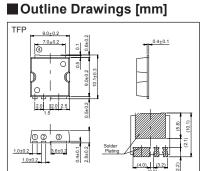
N-CHANNEL SILICON POWER MOSFET

Features

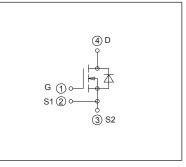
Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (4.2±0.5V) High avalanche durability

Applications

Switching regulators UPS (Uninterruptible Power Supply) **DC-DC converters**



Equivalent circuit schematic



Maximum Ratings and Characteristics

Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks
Ducia Dourse Malfana	VDS	500	V	
Drain-Source Voltage	VDSX	500	V	V _{GS} = -30V
Continuous Drain Current	lo	±16	А	
Pulsed Drain Current	IDP	±64	A	
Gate-Source Voltage	Vgs	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	16	А	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	485	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	22.5	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	4.8	kV/µs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maximum Power Dissipation	PD	1.44	W	Ta=25°C
		225	VV	Tc=25°C
0	Tch	150	°C	
Operating and Storage Temperature range	Tstg	-55 to +150	°C	

Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions		min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BVDSS	I _D =250μA, V _{GS} =0V		500	-	-	V
Gate Threshold Voltage	Vgs (th)	ID=250µA, VDS=VGS		3.7	4.2	4.7	V
Zero Gate Voltage Drain Current		V _{DS} =500V, V _{GS} =0V	Tch=25°C	-	-	25	- μΑ
	IDSS	V _{DS} =400V, V _{GS} =0V	Tch=125°C	-	-	250	
Gate-Source Leakage Current	Igss	V _{GS} =±30V, V _{DS} =0V		-	10	100	nA
Drain-Source On-State Resistance	RDS (on)	ID=8A, VGS=10V		-	0.33	0.38	Ω
Forward Transconductance	g _{fs}	ID=8A, VDS=25V		5.5	11	-	S
Input Capacitance	Ciss	V _{DS} =25V V _{GS} =0V f=1MHz		-	1700	2550	pF
Output Capacitance	Coss			-	210	315	
Reverse Transfer Capacitance	Crss			-	13	19.5	
Turn-On Time	td(on)	V _{cc} =300V V _{cs} =10V I _c =8A R _c =18Ω		-	37	55.5	ns
	tr			-	30	45	
Turn-Off Time	td(off)			-	87	130.5	
	tf			-	17	25.5	
Total Gate Charge	QG	Vcc=250V Ic=16A Vcs=10V		-	48	72	nC
Gate-Source Charge	QGS			-	17	25.5	
Drain-Source Crossover Charge	Qsw			-	7	10.5	
Gate-Drain Charge	QGD			-	18	27	1
Avalanche Capability	lav	L=1.52mH, Tch=25°C	L=1.52mH, Tch=25°C		-	-	A
Diode Forward On-Voltage	Vsd	IF=16A, VGS=0V, Tch=25°C		-	0.90	1.35	V
Reverse Recovery Time	trr	IF=16A, VGS=0V		-	0.46	-	μS
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25°C		-	6.0	-	μC

Thermal Characteristics

Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to case			0.56	°C/W
	Rth (ch-a)	Channel to Ambient			87	°C/W
	Rth (ch-a)	Channel to Ambient Note*6			52	°C/W

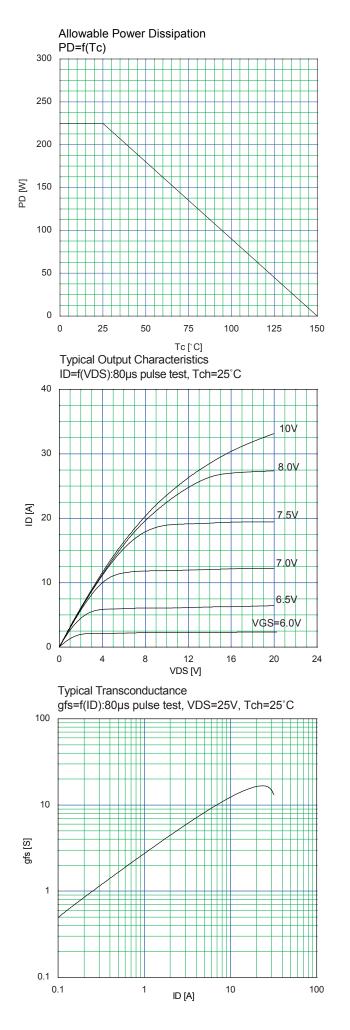
Note *1 : Tch≤150°C

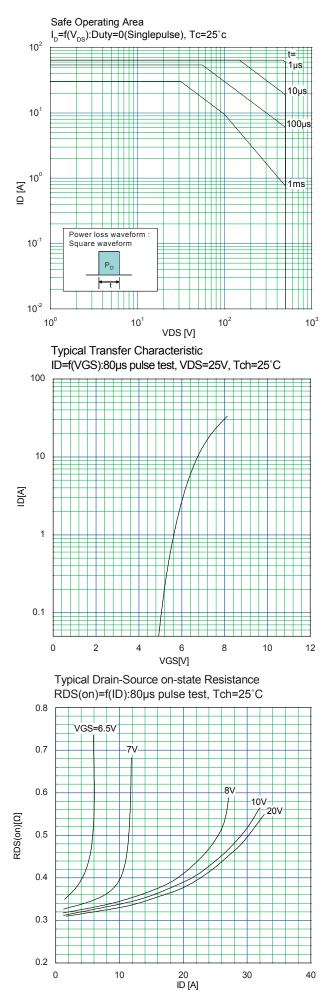
Note *4 : IFS-ID, -di/dt=100A/µs, VccSBVDss, TchS150°C.

Note *2 : Stating Tch=25°C, Ias=5A, L=33.8mH, Vcc=50V, Rg=10 Ω , Eas limited by maximum channel temperature and avalanche current.

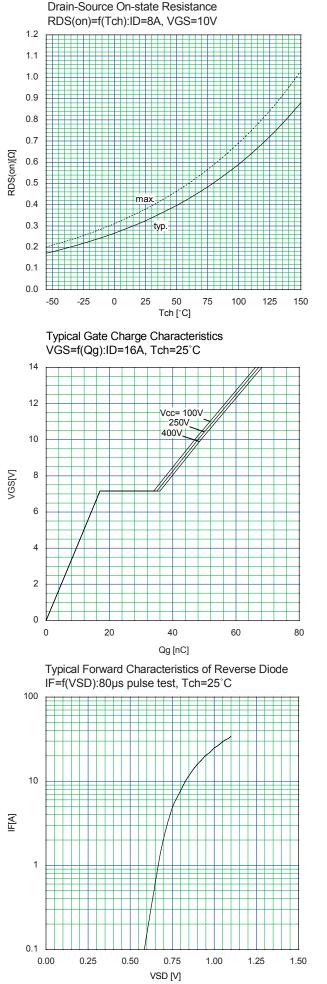
Note *5 : I⊧≤-I_D, dv/dt=6.3kV/Js, Vcc≤BV_{DSS}, Tch≤150°C. Note *6 : Surface mounted on 1000mm², t=1.6mm FR-4 PCB (Drain pad area : 500mm²)

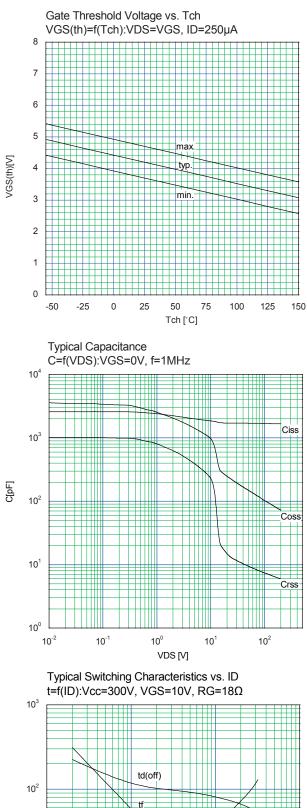
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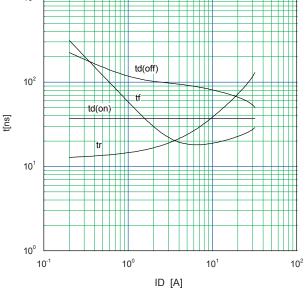




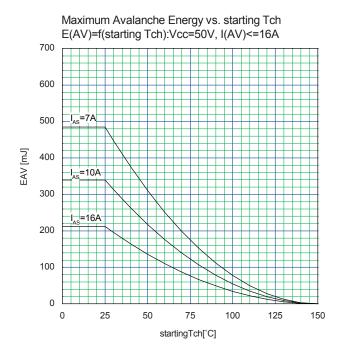
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Maximum Transient ThermalImpedance 2th(ch-c)=f(t):D=0

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